



Atty. Dkt. No. 039153-0685 (AMD H1720)

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Qi XIANG

Title:

STRAINED SILICON MOSFETS

HAVING REDUCED DIFFUSION

OF N-TYPE DOPANTS

Appl. No.:

10/658,611

Filing Date:

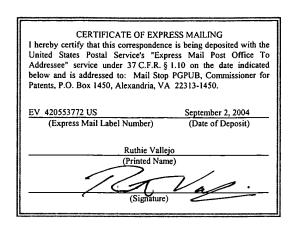
9/9/2003

Examiner:

USPTO EXAMINER

Art Unit:

2812



## REQUEST TO RESCIND PREVIOUS NONPUBLICATION REQUEST 35 U.S.C. 122(b)(2)(B)

Mail Stop PGPUB Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Applicant hereby rescinds the previous request that the above-identified application not be published under 35 U.S.C. 122(b).

Applicant furthermore hereby provides the notice to the Patent Office required by 35 U.S.C. 122(b)(2)(B)(iii) and 37 C.F.R. 1.213(c) that an application directed to the invention disclosed in the above-identified application was submitted in another country, or under a multilateral international agreement, that requires publication of applications eighteen months

after filing. This notice is being provided within forty-five days after the date of the filing of such foreign or international application.

Respectfully submitted,

Date / September 04
FOLEY & LARDNER LLP

Customer Number: 23392

Telephone: (310) 975-7964

Facsimile: (310) 557-8475

Ronald Coslick

Attorney for Applicant Registration No. 36,489